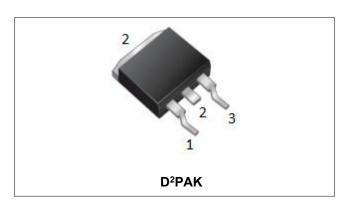


## MBRB10100CT

Technical Data Data Sheet N0191, Rev. A



# **MBRB10100CT SCHOTTKY RECTIFIER**



#### Features

- 150°C TJ operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

#### **Applications**

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

#### **\*** 2

**Circuit Diagram** 

Base common Cathode

### **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	100	V
Average Rectified Forward Current (Per Device)	lf (AV)	50% duty cycle @Tc=105°C, rectangular wave form	5(Per Leg) 10(Per Device)	А
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I <sub>FSM</sub>	8.3ms, Half Sine pulse	120	А

### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop	V <sub>F1</sub>	@ 5A, Pulse, T <sub>J</sub> = 25 °C	0.77	0.85	V
(Per Leg) *	V <sub>F2</sub>	@ 5A, Pulse, T <sub>J</sub> = 125 °C	0.62	0.75	V
Reverse Current (Per Leg) *	I <sub>R1</sub>	$@V_R = rated V_{R_i} T_J = 25 \circ C$	0.6	1.0	mA
	I <sub>R2</sub>	$@V_R = rated V_{R_j} T_J = 125 \ ^{\circ}C$	8	15	mA
Junction Capacitance(Per Leg)	Ст	$@V_{R} = 5V, T_{C} = 25 \ ^{\circ}C, f_{SIG} = 1MHz$	130	300	pF
Series Inductance(Per Leg)	Ls	Measured lead to lead 5 mm from package body	8.0	-	nH
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

\* Pulse width < 300 µs, duty cycle < 2%

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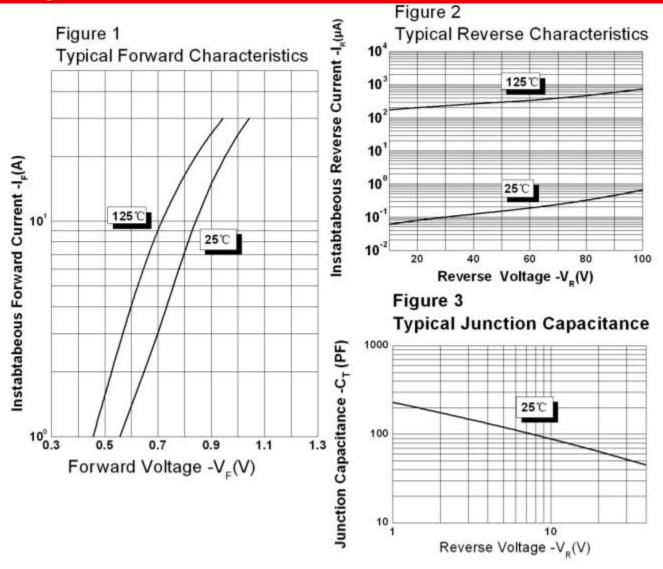
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RoHS 🗭

## **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case(Per Leg)	$R_{ ext{ heta}JC}$	DC operation	6	°C/W
Approximate Weight	wt	-	1.85	g
Case Style	D <sup>2</sup> PAK			

## **Ratings and Characteristics Curves**



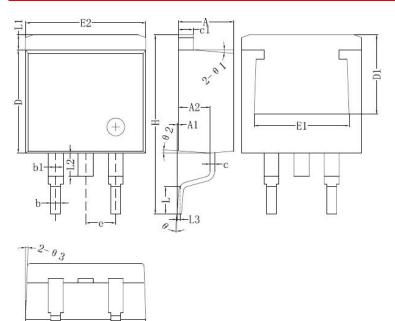


## **MBRB10100CT**

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### Mechanical Dimensions D<sup>2</sup>PAK



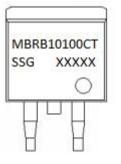
Symbol	Dimensions in millimeter			
	Min.	Typical	Max.	
A	4.47	4.70	4.85	
A1	0	0.10	0.25	
A2	2.59	2.69	2.89	
b	0.71	0.81	0.96	
b1	1.17	1.27	1.37	
C	0.31	0.38	0.61	
c1	1.17	1.27	1.37	
D	8.50	8.70	8.90	
D1	6.40			
E	10.01	10.16	10.31	
E1	7.6			
E2	9.98	10.08	10.31	
е		2.54		
Н	14.6	15.1	15.6	
L	2.00	2.30	2.74	
L1	1.12	1.27	1.42	
L2	1.30		2.20	
L3		0.25BSC		
е	0	-	8°	
e1		5°		
e2		4°		
e3		4°		

## **Ordering Information**

Device	Package	Shipping
MBRB10100CT	D <sup>2</sup> PAK	800pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

## **Marking Diagram**



#### Where XXXXX is YYWWL

MBR = Device Type

В

10

100

СТ

YΥ

ww

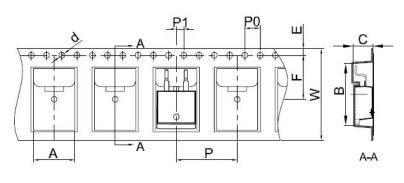
L

SSG

- = Package type = Forward Current (10A)
- = Reverse Voltage(100V)
- = Configuration
- = SSG
- = Year = Week
- = Lot Number

Epoxy resin UL:94V-0

## **Carrier Tape Specification D<sup>2</sup>PAK**



SYMBOL	Millimeters		
	Min.	Max.	
А	10.70	10.90	
В	16.03	16.23	
С	5.11	5.31	
d	1.45	1.65	
E	1.65	1.85	
F	11.40	11.60	
P0	3.90	4.10	
Р	15.90	16.10	
P1	1.90	2.10	
W	23.90	24.30	

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Cautions: Molding resin



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## MBRB10100CT



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